

Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of <http://www.nxp.com>, <http://www.philips.com/> or <http://www.semiconductors.philips.com/>, use **<http://www.nexperia.com>**

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use **salesaddresses@nexperia.com** (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

- © **Nexperia B.V. (year). All rights reserved.**

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

74HC4067-Q100; 74HCT4067-Q100

16-channel analog multiplexer/demultiplexer

Rev. 1 — 22 May 2015

Product data sheet

1. General description

The 74HC4067-Q100; 74HCT4067-Q100 is a single-pole 16-throw analog switch (SP16T) suitable for use in analog or digital 16:1 multiplexer/demultiplexer applications. The switch features four digital select inputs (S0, S1, S2 and S3), sixteen independent inputs/outputs (Yn), a common input/output (Z) and a digital enable input (\overline{E}). When \overline{E} is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Input levels S0, S1, S2, S3 and \overline{E} inputs:
 - ◆ For 74HC4067-Q100: CMOS level
 - ◆ For 74HCT4067-Q100: TTL level
- Low ON resistance:
 - ◆ $80\text{ }\Omega$ (typical) at $V_{CC} = 4.5\text{ V}$
 - ◆ $70\text{ }\Omega$ (typical) at $V_{CC} = 6.0\text{ V}$
 - ◆ $60\text{ }\Omega$ (typical) at $V_{CC} = 9.0\text{ V}$
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Typical 'break before make' built-in

3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating



4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC4067D-Q100	−40 °C to +125 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1
74HCT4067D-Q100				
74HC4067PW-Q100	−40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1
74HCT4067PW-Q100				
74HC4067BQ-Q100	−40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 × 5.5 × 0.85 mm	SOT815-1
74HCT4067BQ-Q100				

5. Functional diagram

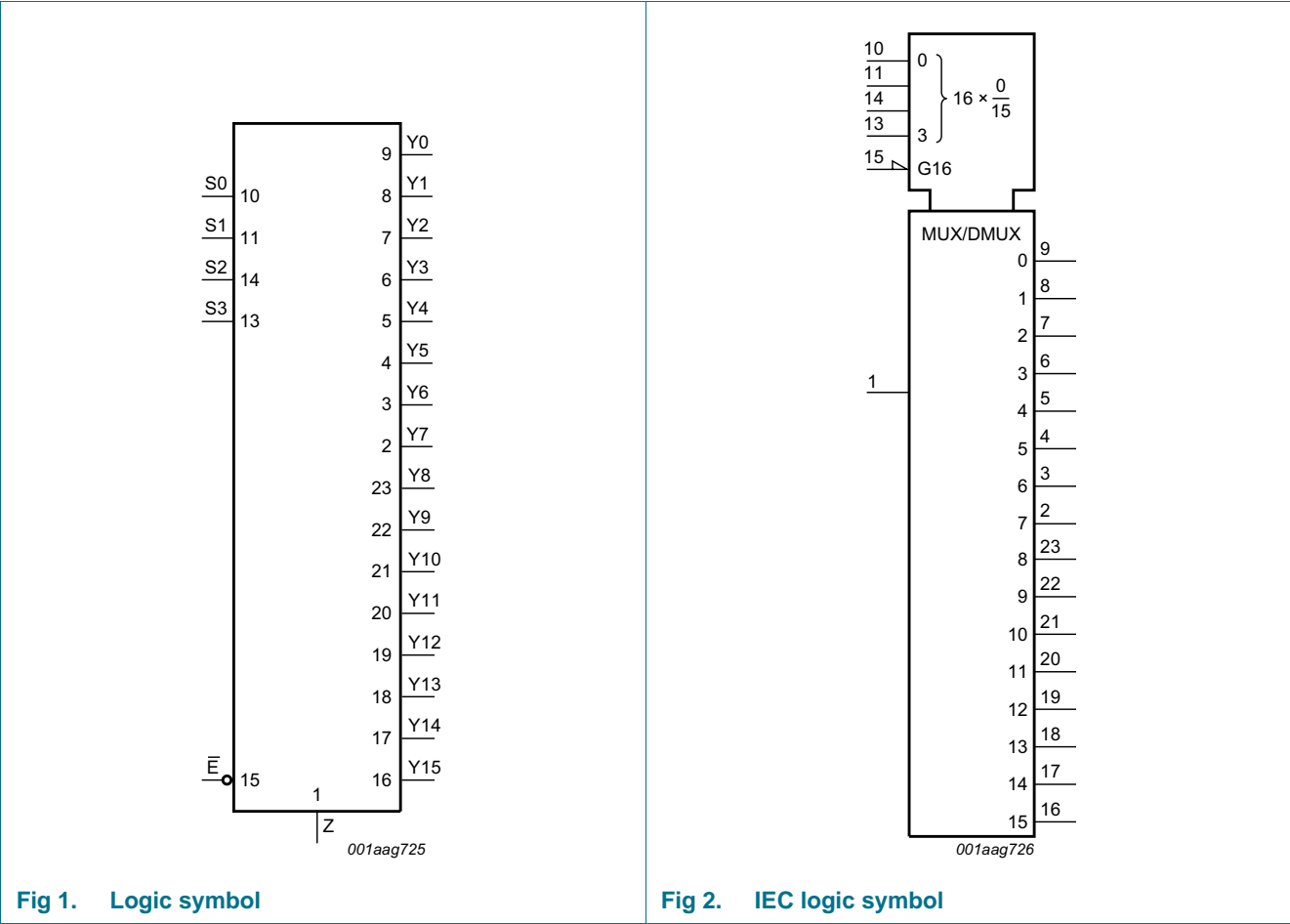


Fig 3. Schematic diagram (one switch)

Fig 4. Functional diagram

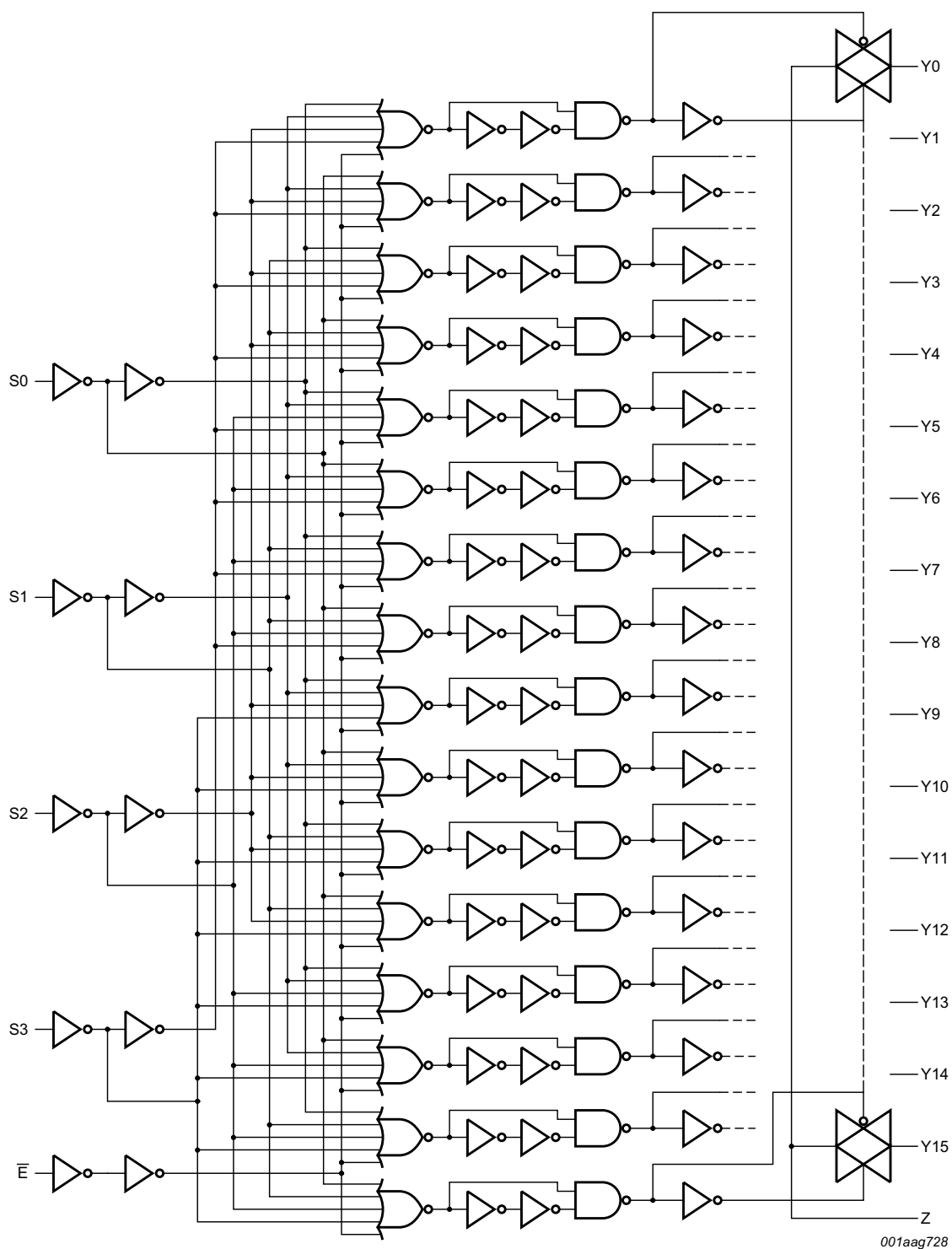
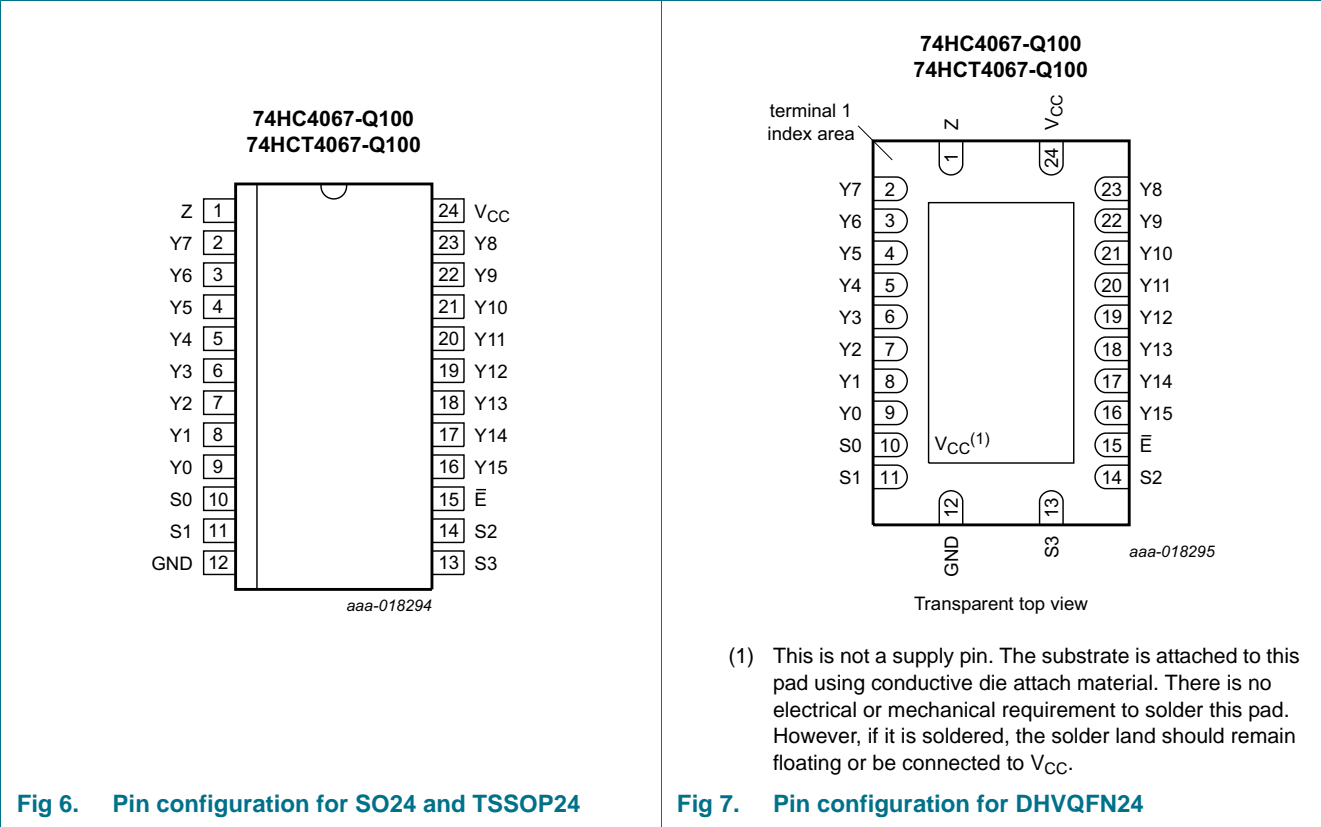


Fig 5. Logic diagram

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Z	1	common input or output
Y7, Y6, Y5, Y4, Y3, Y2, Y1, Y0, Y15, Y14, Y13, Y12, Y11, Y10, Y9, Y8	2, 3, 4, 5, 6, 7, 8, 9, 16, 17, 18, 19, 20, 21, 22, 23	independent input or output
S0, S1, S3, S2	10, 11, 13, 14	address input 0
GND	12	ground (0 V)
\overline{E}	15	enable input (active LOW)
V _{CC}	24	supply voltage

7. Functional description

Table 3. Function table^[1]

Inputs					Channel ON
\overline{E}	S3	S2	S1	S0	
L	L	L	L	L	Y0 to Z
L	L	L	L	H	Y1 to Z
L	L	L	H	L	Y2 to Z
L	L	L	H	H	Y3 to Z
L	L	H	L	L	Y4 to Z
L	L	H	L	H	Y5 to Z
L	L	H	H	L	Y6 to Z
L	L	H	H	H	Y7 to Z
L	H	L	L	L	Y8 to Z
L	H	L	L	H	Y9 to Z
L	H	L	H	L	Y10 to Z
L	H	L	H	H	Y11 to Z
L	H	H	L	L	Y12 to Z
L	H	H	L	H	Y13 to Z
L	H	H	H	L	Y14 to Z
L	H	H	H	H	Y15 to Z
H	X	X	X	X	-

[1] H = HIGH voltage level;
L = LOW voltage level;
X = don't care.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage	^[1]	-0.5	+11.0	V
I_{IK}	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	± 20	mA
I_{SK}	switch clamping current	$V_{SW} < -0.5\text{ V}$ or $V_{SW} > V_{CC} + 0.5\text{ V}$	-	± 20	mA
I_{SW}	switch current	$V_{SW} = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$	-	± 25	mA
I_{CC}	supply current		-	+50	mA
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C			
		SO24 package [2]	-	500	mW
		SSOP24 package [3]	-	500	mW
		TSSOP24 package [3]	-	500	mW
		DHVQFN24 package [4]	-	500	mW
P	power dissipation	per switch	-	100	mW

- [1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Y_n, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Y_n. In this case there is no limit for the voltage drop across the switch, but the voltages at Y_n and Z may not exceed V_{CC} or GND.
- [2] For SO24 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
- [3] For TSSOP24 package: P_{tot} derates linearly with 5.5 mW/K above 60 °C.
- [4] For DHVQFN24 package: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
74HC4067-Q100						
V _{CC}	supply voltage		2.0	5.0	10.0	V
V _I	input voltage		GND	-	V _{CC}	V
V _{SW}	switch voltage		GND	-	V _{CC}	V
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	ns
		V _{CC} = 4.5 V	-	1.67	139	ns
		V _{CC} = 6.0 V	-	-	83	ns
		V _{CC} = 10.0 V	-	-	31	ns
T _{amb}	ambient temperature		-40	+25	+125	°C
74HCT4067-Q100						
V _{CC}	supply voltage		4.5	5.0	5.5	V
V _I	input voltage		GND	-	V _{CC}	V
V _{SW}	switch voltage		GND	-	V _{CC}	V
Δt/ΔV	input transition rise and fall rate	V _{CC} = 4.5 V	-	1.67	139	ns
T _{amb}	ambient temperature		-40	+25	+125	°C

10. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4067-Q100 and 74HCT4067-Q100

$V_I = V_{IH}$ or V_{IL} ; for test circuit see [Figure 8](#).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

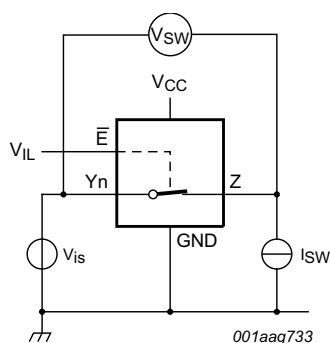
V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

For 74HC4067-Q100: $V_{CC} - GND = 2.0\text{ V}, 4.5\text{ V}, 6.0\text{ V}$ and 9.0 V .

For 74HCT4067-Q100: $V_{CC} - GND = 4.5\text{ V}$.

Symbol	Parameter	Conditions	25 °C		–40 °C to +125 °C		Unit
			Typ	Max	Max (85 °C)	Max (125 °C)	
$R_{ON(peak)}$	ON resistance (peak)	$V_{is} = V_{CC}$ to GND					
		$V_{CC} = 2.0\text{ V}; I_{SW} = 100\text{ }\mu\text{A}$ [1]	-	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}; I_{SW} = 1000\text{ }\mu\text{A}$	110	180	225	270	Ω
		$V_{CC} = 6.0\text{ V}; I_{SW} = 1000\text{ }\mu\text{A}$	95	160	200	240	Ω
		$V_{CC} = 9.0\text{ V}; I_{SW} = 1000\text{ }\mu\text{A}$	75	130	165	195	Ω
$R_{ON(rail)}$	ON resistance (rail)	$V_{is} = GND$ or V_{CC}					
		$V_{CC} = 2.0\text{ V}; I_{SW} = 100\text{ }\mu\text{A}$ [1]	150	-	-	-	
		$V_{CC} = 4.5\text{ V}; I_{SW} = 1000\text{ }\mu\text{A}$	90	160	200	240	Ω
		$V_{CC} = 6.0\text{ V}; I_{SW} = 1000\text{ }\mu\text{A}$	80	140	175	210	Ω
		$V_{CC} = 9.0\text{ V}; I_{SW} = 1000\text{ }\mu\text{A}$	70	120	150	180	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_{is} = V_{CC}$ to GND					
		$V_{CC} = 2.0\text{ V}$ [1]	-	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}$	9	-	-	-	Ω
		$V_{CC} = 6.0\text{ V}$	8	-	-	-	Ω
		$V_{CC} = 9.0\text{ V}$	6	-	-	-	Ω

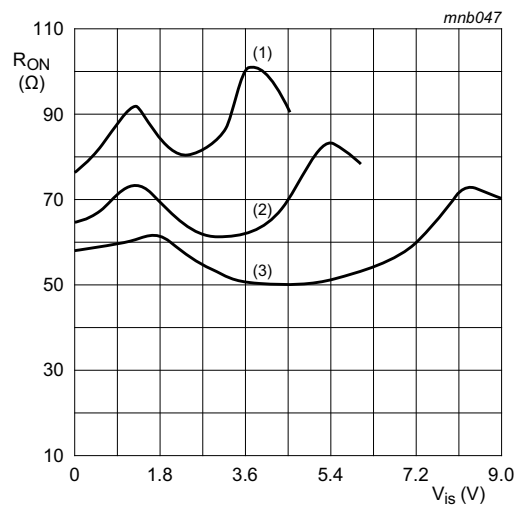
- [1] At supply voltages ($V_{CC} - GND$) approaching 2 V, the analog switch ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.



$V_{is} = 0 \text{ V to } V_{CC}$

$$R_{ON} = \frac{V_{SW}}{I_{SW}}$$

Fig 8. Test circuit for measuring R_{ON}



$V_{is} = 0 \text{ V to } V_{CC}$

- (1) $V_{CC} = 4.5 \text{ V}$
- (2) $V_{CC} = 6.0 \text{ V}$
- (3) $V_{CC} = 9.0 \text{ V}$

Fig 9. Typical R_{ON} as a function of input voltage V_{is}

Table 7. Static characteristics 74HC4067-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25 \text{ }^{\circ}\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	V
		$V_{CC} = 4.5 \text{ V}$	3.15	2.4	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	V
		$V_{CC} = 9.0 \text{ V}$	6.3	4.7	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	0.8	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.80	V
		$V_{CC} = 9.0 \text{ V}$	-	4.3	2.70	V
I_I	input leakage current	$V_I = V_{CC} \text{ or GND}$				
		$V_{CC} = 6.0 \text{ V}$	-	-	± 0.1	μA
		$V_{CC} = 10.0 \text{ V}$	-	-	± 0.2	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; V_{SW} = V_{CC} - \text{GND}; \text{ see Figure 10}$				
		per channel	-	-	± 0.1	μA
		all channels	-	-	± 0.8	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}; V_{SW} = V_{CC} - \text{GND}; \text{ see Figure 11}$	-	-	± 0.8	μA

Table 7. Static characteristics 74HC4067-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = GND or V _{CC} ; V _{os} = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	8.0	μA
		V _{CC} = 10.0 V	-	-	16.0	μA
C _I	input capacitance		-	3.5	-	pF
T _{amb} = −40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.50	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.80	V
		V _{CC} = 9.0 V	-	-	2.70	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10.0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} – GND; see Figure 10				
		per channel	-	-	±1.0	μA
		all channels	-	-	±8.0	μA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10.0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} – GND; see Figure 11	-	-	±8.0	μA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = GND or V _{CC} ; V _{os} = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	80.0	μA
		V _{CC} = 10.0 V	-	-	160	μA
T _{amb} = −40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.50	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.80	V
		V _{CC} = 9.0 V	-	-	2.70	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA

Table 7. Static characteristics 74HC4067-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10.0\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 10				
		per channel	-	-	± 1.0	μA
		all channels	-	-	± 8.0	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10.0\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 11	-	-	± 8.0	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = \text{GND}$ or V_{CC} ; $V_{os} = V_{CC}$ or GND				
		$V_{CC} = 6.0\text{ V}$	-	-	160	μA
		$V_{CC} = 10.0\text{ V}$	-	-	320	μA

Table 8. Static characteristics 74HCT4067-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

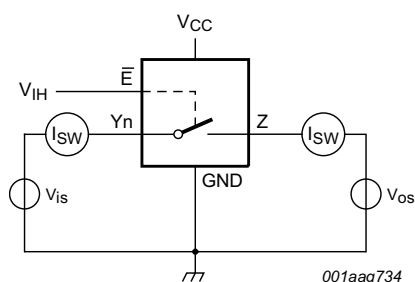
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25\text{ }^{\circ}\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	1.2	0.8	V
I_I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$	-	-	± 0.1	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 10				
		per channel	-	-	± 0.1	μA
		all channels	-	-	± 0.8	μA
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 11	-	-	± 0.8	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = \text{GND}$ or V_{CC} ; $V_{os} = V_{CC}$ or GND; $V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	8.0	μA
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1\text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5\text{ V to }5.5\text{ V}$				
		pin \overline{E}	-	60	216	μA
		pin Sn	-	50	180	μA
C_I	input capacitance		-	3.5	-	pF
$T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	0.8	V
I_I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$	-	-	± 1.0	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - \text{GND}$; see Figure 10				
		per channel	-	-	± 1.0	μA
		all channels	-	-	± 8.0	μA

Table 8. Static characteristics 74HCT4067-Q100 ...continued

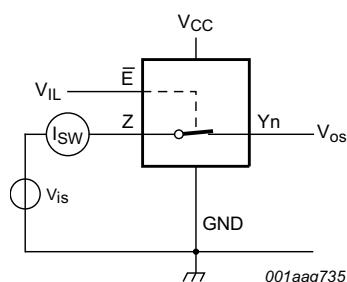
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _{S(ON)}	ON-state leakage current	V _{CC} = 5.5 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} – GND; see Figure 11	-	-	±8.0	μA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = GND or V _{CC} ; V _{os} = V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V	-	-	80.0	μA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} – 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V				
		pin $\overline{\text{E}}$	-	-	270	μA
		pin Sn	-	-	225	μA
T _{amb} = –40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V	-	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 5.5 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} – GND; see Figure 10				
		per channel	-	-	±1.0	μA
		all channels	-	-	±8.0	μA
I _{S(ON)}	ON-state leakage current	V _{CC} = 5.5 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} – GND; see Figure 11	-	-	±8.0	μA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = GND or V _{CC} ; V _{os} = V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V	-	-	160	μA
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} – 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V				
		pin $\overline{\text{E}}$	-	-	294	μA
		pin Sn	-	-	245	μA



$V_{is} = V_{CC}$ and $V_{os} = \text{GND}$
 $V_{is} = \text{GND}$ and $V_{os} = V_{CC}$

Fig 10. Test circuit for measuring OFF-state leakage current

$V_{is} = V_{CC}$ and $V_{os} = \text{open}$
 $V_{is} = \text{GND}$ and $V_{os} = \text{open}$

Fig 11. Test circuit for measuring ON-state leakage current

11. Dynamic characteristics

Table 9. Dynamic characteristics 74HC4067-Q100

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$ unless specified otherwise; for test circuit see [Figure 14](#).

V_{is} is the input voltage at a Y_n or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Y_n or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25 °C		–40 °C to +125 °C		Unit
			Typ	Max	Max (85 °C)	Max (125 °C)	
t_{pd}	propagation delay	Y_n to Z ; see Figure 12 [1][2]					
		$V_{CC} = 2.0\text{ V}$	25	75	95	110	ns
		$V_{CC} = 4.5\text{ V}$	9	15	19	22	ns
		$V_{CC} = 6.0\text{ V}$	7	13	16	19	ns
		$V_{CC} = 9.0\text{ V}$	5	9	11	14	ns
		Z to Y_n					
		$V_{CC} = 2.0\text{ V}$	18	60	75	90	ns
		$V_{CC} = 4.5\text{ V}$	6	12	15	18	ns
		$V_{CC} = 6.0\text{ V}$	5	10	13	15	ns
		$V_{CC} = 9.0\text{ V}$	4	8	10	12	ns
t_{off}	turn-off time	\overline{E} to Y_n ; see Figure 13 [3]					
		$V_{CC} = 2.0\text{ V}$	74	250	315	375	ns
		$V_{CC} = 4.5\text{ V}$	27	50	63	75	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	27	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	22	43	54	64	ns
		$V_{CC} = 9.0\text{ V}$	20	38	48	57	ns
		S_n to Y_n					
		$V_{CC} = 2.0\text{ V}$	83	250	315	375	ns
		$V_{CC} = 4.5\text{ V}$	30	50	63	75	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	29	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	24	43	54	64	ns
		$V_{CC} = 9.0\text{ V}$	21	38	48	57	ns
		\overline{E} to Z					
		$V_{CC} = 2.0\text{ V}$	85	275	345	415	ns
		$V_{CC} = 4.5\text{ V}$	31	55	69	83	ns
		$V_{CC} = 6.0\text{ V}$	25	47	59	71	ns
		$V_{CC} = 9.0\text{ V}$	24	42	53	63	ns
		S_n to Z					
		$V_{CC} = 2.0\text{ V}$	94	290	365	435	ns
		$V_{CC} = 4.5\text{ V}$	34	58	73	87	ns
		$V_{CC} = 6.0\text{ V}$	27	47	62	74	ns
		$V_{CC} = 9.0\text{ V}$	25	45	56	68	ns

Table 9. Dynamic characteristics 74HC4067-Q100 ...continued

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$ unless specified otherwise; for test circuit see [Figure 14](#).

V_{is} is the input voltage at a Yn or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Yn or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25 °C		–40 °C to +125 °C		Unit
			Typ	Max	Max (85 °C)	Max (125 °C)	
t_{on}	turn-on time	\bar{E} to Yn; see Figure 13 [4]					
		$V_{CC} = 2.0\text{ V}$	80	275	345	415	ns
		$V_{CC} = 4.5\text{ V}$	29	55	69	83	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	26	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	23	47	59	71	ns
		$V_{CC} = 9.0\text{ V}$	17	42	53	63	ns
		Sn to Yn					
		$V_{CC} = 2.0\text{ V}$	88	300	375	450	ns
		$V_{CC} = 4.5\text{ V}$	32	60	75	90	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	29	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$	26	51	64	77	ns
		$V_{CC} = 9.0\text{ V}$	18	45	56	68	ns
		\bar{E} to Z					
		$V_{CC} = 2.0\text{ V}$	85	275	345	415	ns
		$V_{CC} = 4.5\text{ V}$	31	55	69	83	ns
		$V_{CC} = 6.0\text{ V}$	25	47	59	71	ns
		$V_{CC} = 9.0\text{ V}$	18	42	53	63	ns
		Sn to Z					
		$V_{CC} = 2.0\text{ V}$	94	300	375	450	ns
		$V_{CC} = 4.5\text{ V}$	34	60	75	90	ns
		$V_{CC} = 6.0\text{ V}$	27	51	64	77	ns
		$V_{CC} = 9.0\text{ V}$	19	45	56	68	ns
C_{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [5]	29	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] Due to higher Z terminal capacitance (16 switches versus 1) the delay figures to the Z terminal are higher than those to the Y terminal.

[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

[4] t_{off} is the same as t_{PZH} and t_{PZL} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

$\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ = sum of outputs;

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics 74HCT4067-Q100

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$ unless specified otherwise; for test circuit see [Figure 14](#).

V_{is} is the input voltage at a Y_n or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Y_n or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25 °C		–40 °C to +125 °C		Unit
			Typ	Max	Max (85 °C)	Max (125 °C)	
t_{pd}	propagation delay	Y_n to Z ; see Figure 12 [1][2]					
		$V_{CC} = 4.5\text{ V}$	9	15	19	22	ns
		Z to Y_n					
		$V_{CC} = 4.5\text{ V}$	6	12	15	18	ns
t_{off}	turn-off time	\overline{E} to Y_n ; see Figure 13 [3]					
		$V_{CC} = 4.5\text{ V}$	26	55	69	83	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	26	-	-	-	ns
		S_n to Y_n					
		$V_{CC} = 4.5\text{ V}$	31	55	69	83	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	30	-	-	-	ns
		\overline{E} to Z					
		$V_{CC} = 4.5\text{ V}$	30	60	75	90	ns
		S_n to Z					
		$V_{CC} = 4.5\text{ V}$	35	60	75	90	ns
t_{on}	turn-on time	\overline{E} to Y_n ; see Figure 13 [4]					
		$V_{CC} = 4.5\text{ V}$	32	60	75	90	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	32	-	-	-	ns
		S_n to Y_n					
		$V_{CC} = 4.5\text{ V}$	35	60	75	90	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	33	-	-	-	ns
		\overline{E} to Z					
		$V_{CC} = 4.5\text{ V}$	38	65	81	98	ns
		S_n to Z					
		$V_{CC} = 4.5\text{ V}$	38	65	81	98	ns
C_{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $(V_{CC} - 1.5\text{ V})$ [5]	29	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] Due to higher Z terminal capacitance (16 switches versus 1) the delay figures to the Z terminal are higher than those to the Y terminal.

[3] t_{on} is the same as t_{PHZ} and t_{PLZ} .

[4] t_{off} is the same as t_{PZH} and t_{PZL} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

$\sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ = sum of outputs;

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

12. Waveforms

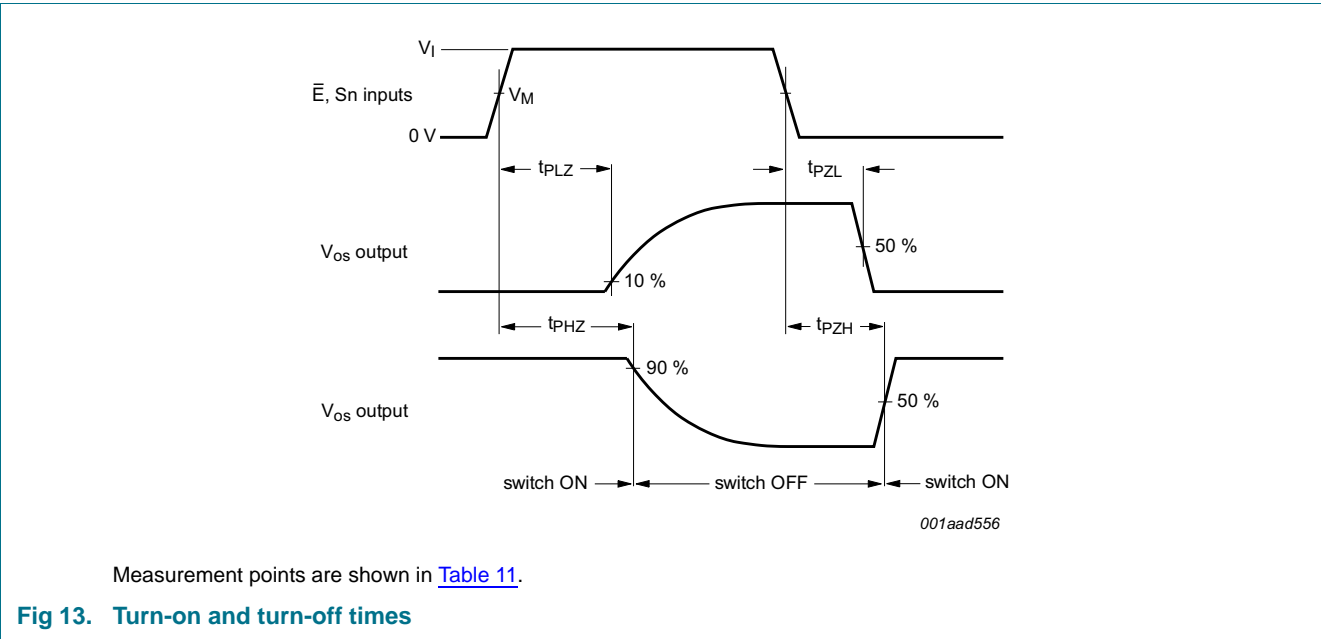
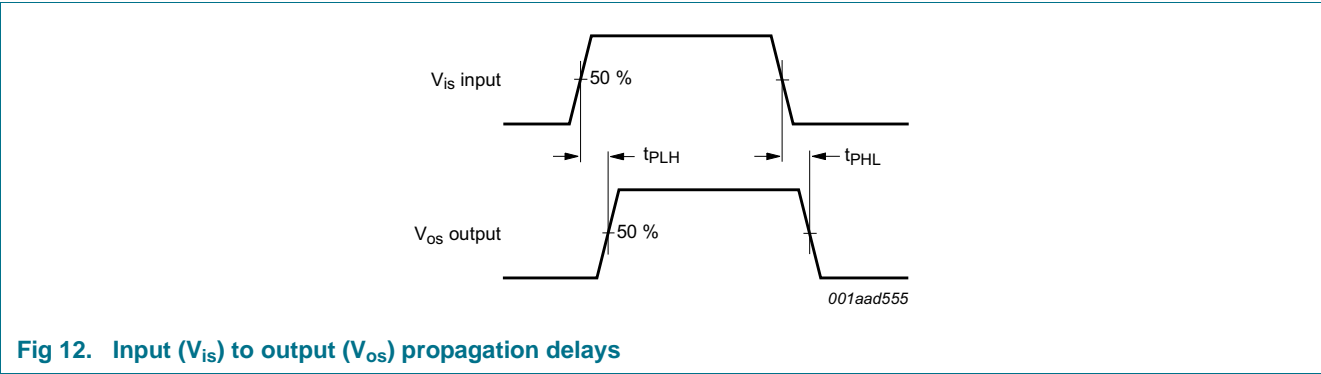


Table 11. Measurement points

Type	V_I	V_M
74HC4067-Q100	V_{CC}	$0.5V_{CC}$
74HCT4067-Q100	3.0 V	1.3 V

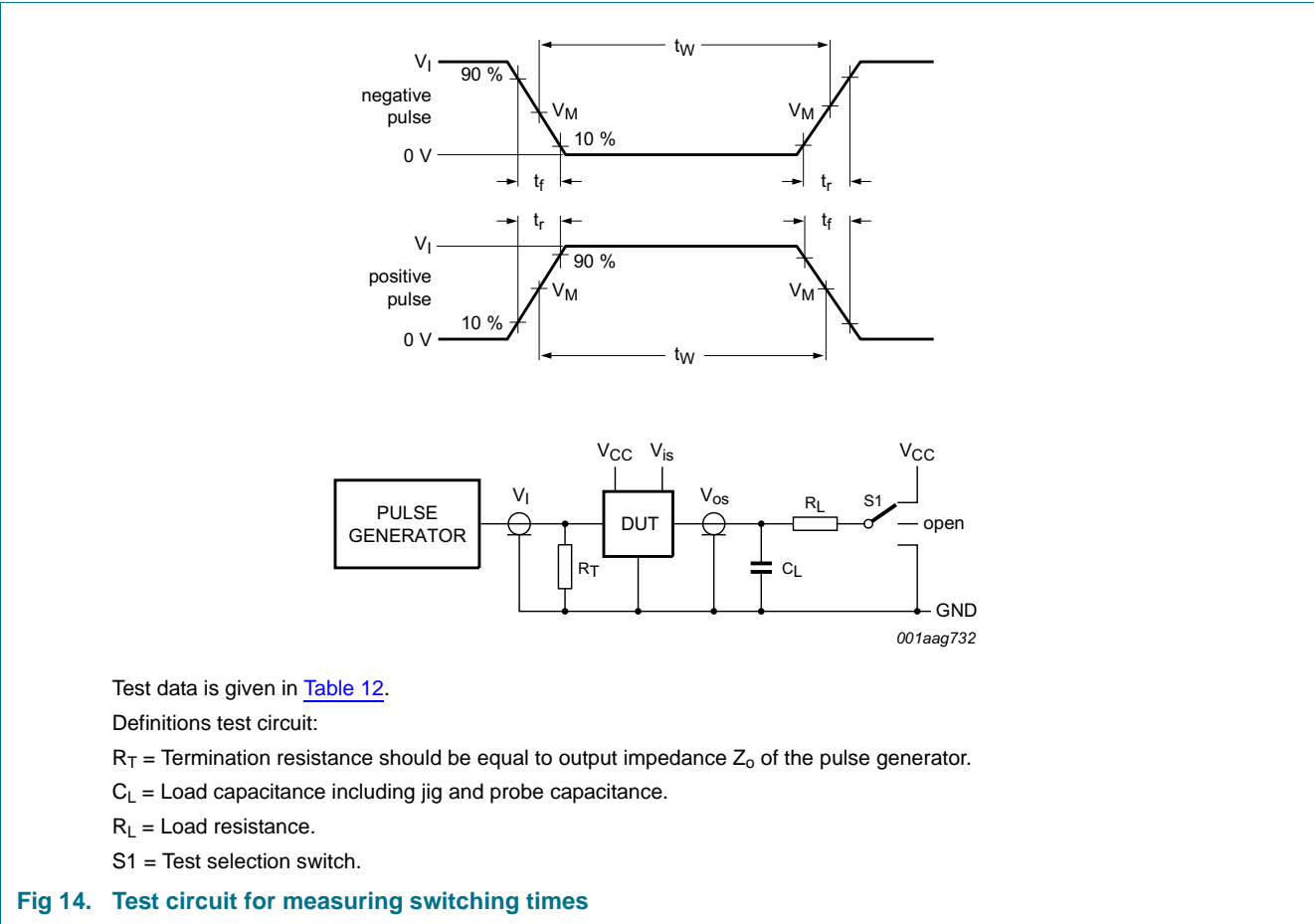


Table 12. Test data

Test	Input				Output		S1 position
	Control \overline{E}	Address Sn	Switch Yn (Z)	t_r, t_f	Switch Z (Yn)		
	V_I [4]	V_I [4]	V_{is}		C_L	R_L	
t_{PHL}, t_{PLH}	GND	GND or V_{CC}	GND to V_{CC}	6 ns	50 pF	-	open
t_{PHZ}, t_{PZH}	GND to V_{CC}	GND to V_{CC}	V_{CC}	6 ns	50 pF, 15 pF	1 k Ω	GND
t_{PLZ}, t_{PZL}	GND to V_{CC}	GND to V_{CC}	GND	6 ns	50 pF, 15 pF	1 k Ω	V_{CC}

[1] For 74HCT4067-Q100: maximum input voltage $V_I = 3.0$ V.

13. Additional dynamic characteristics

Table 13. Additional dynamic characteristics

Recommended conditions and typical values; $GND = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

V_{is} is the input voltage at a Y_n or Z terminal, whichever is assigned as an input.

V_{os} is the output voltage at a Y_n or Z terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$; see Figure 15				
		$f_i = 1\text{ kHz}$				
		$V_{CC} = 4.5\text{ V}$; $V_{is(p-p)} = 4.0\text{ V}$	-	0.04	-	%
		$V_{CC} = 9.0\text{ V}$; $V_{is(p-p)} = 8.0\text{ V}$	-	0.02	-	%
		$f_i = 10\text{ kHz}$				
		$V_{CC} = 4.5\text{ V}$; $V_{is(p-p)} = 4.0\text{ V}$	-	0.12	-	%
		$V_{CC} = 9.0\text{ V}$; $V_{is(p-p)} = 8.0\text{ V}$	-	0.06	-	%
α_{iso}	isolation (OFF-state)	$R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; see Figure 16 [1]				
		$V_{CC} = 4.5\text{ V}$	-	-50	-	dB
		$V_{CC} = 9.0\text{ V}$	-	-50	-	dB
$f_{(-3dB)}$	-3 dB frequency response	$R_L = 50\text{ }\Omega$; $C_L = 10\text{ pF}$; see Figure 17 [2]				
		$V_{CC} = 4.5\text{ V}$	-	90	-	MHz
		$V_{CC} = 9.0\text{ V}$	-	100	-	MHz
C_{sw}	switch capacitance	independent pins Y	-	5	-	pF
		common pin Z	-	45	-	pF

[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for $f_i = 1\text{ MHz}$ (0 dBm = 1 mW into 50 Ω). After set-up, f_i is increased to obtain a reading of -3 dB at V_{os} .

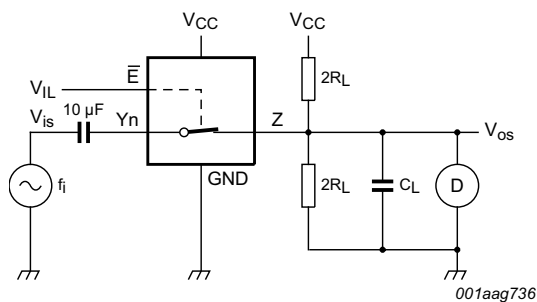
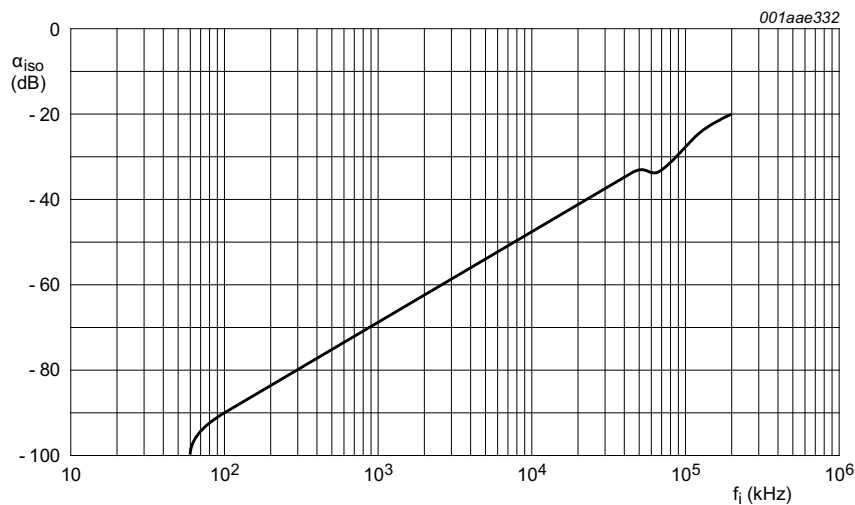
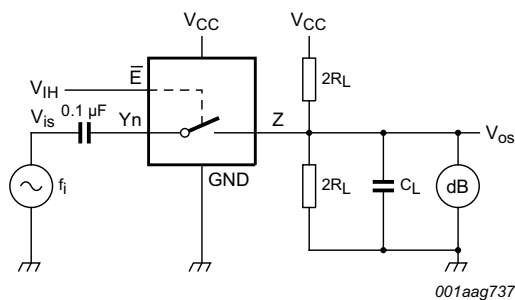


Fig 15. Test circuit for measuring total harmonic distortion



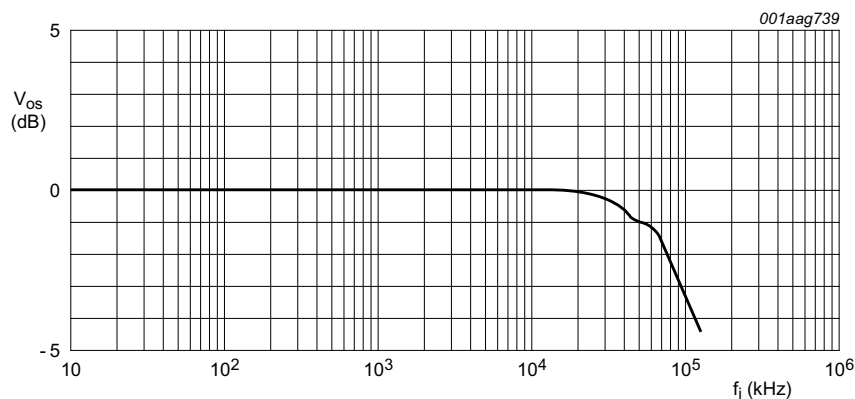
a. Isolation (OFF-state)



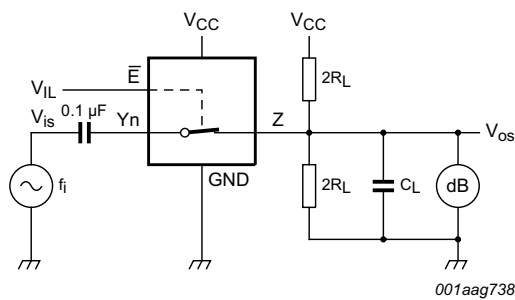
b. Test circuit

$V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $R_L = 600\text{ }\Omega$; $R_{source} = 1\text{ k}\Omega$.

Fig 16. Isolation (OFF-state) as a function of frequency



a. Typical -3 dB frequency response



b. Test circuit

$V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $R_L = 50\text{ }\Omega$; $R_{source} = 1\text{ k}\Omega$.

Fig 17. -3 dB frequency response

14. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1

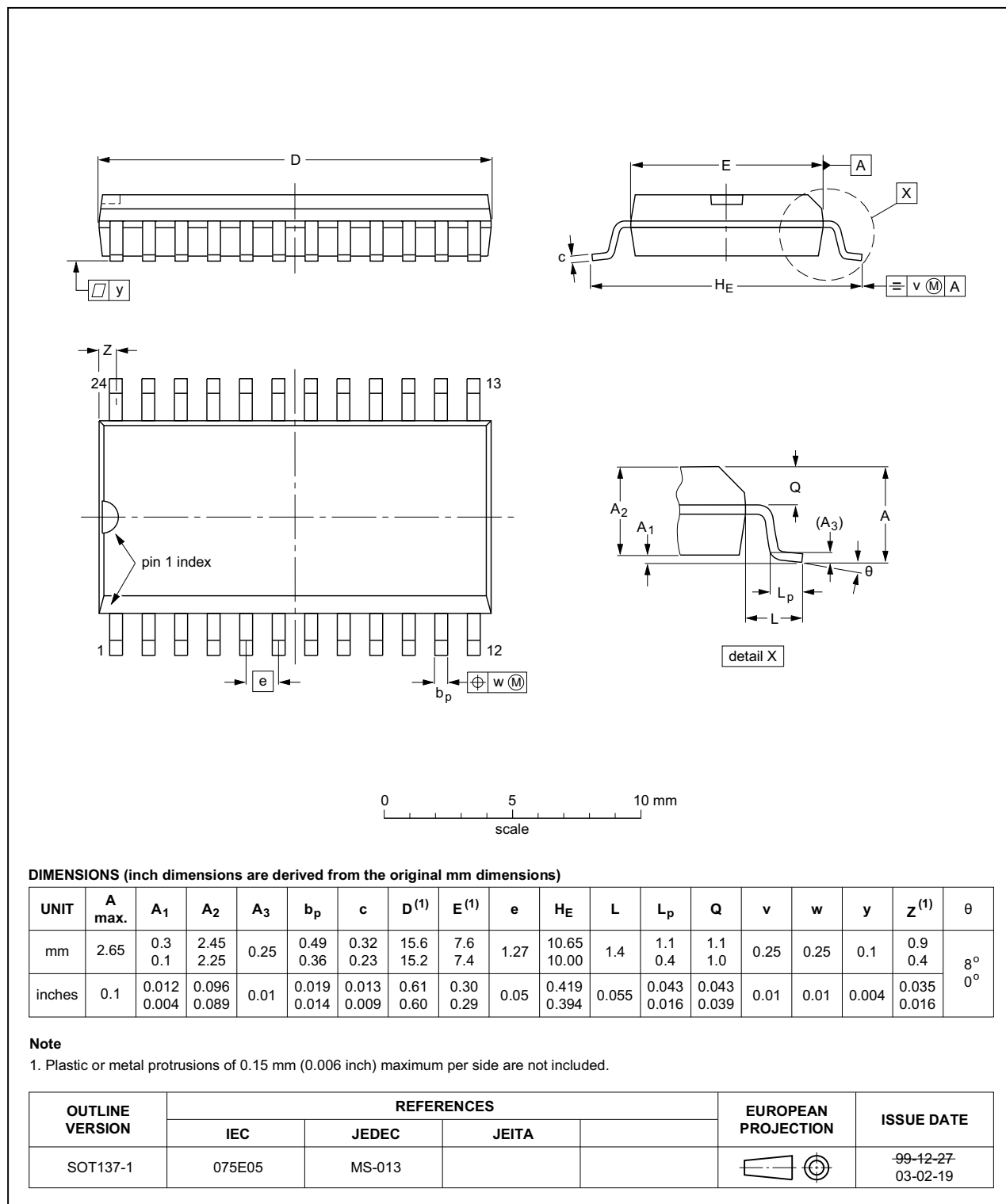
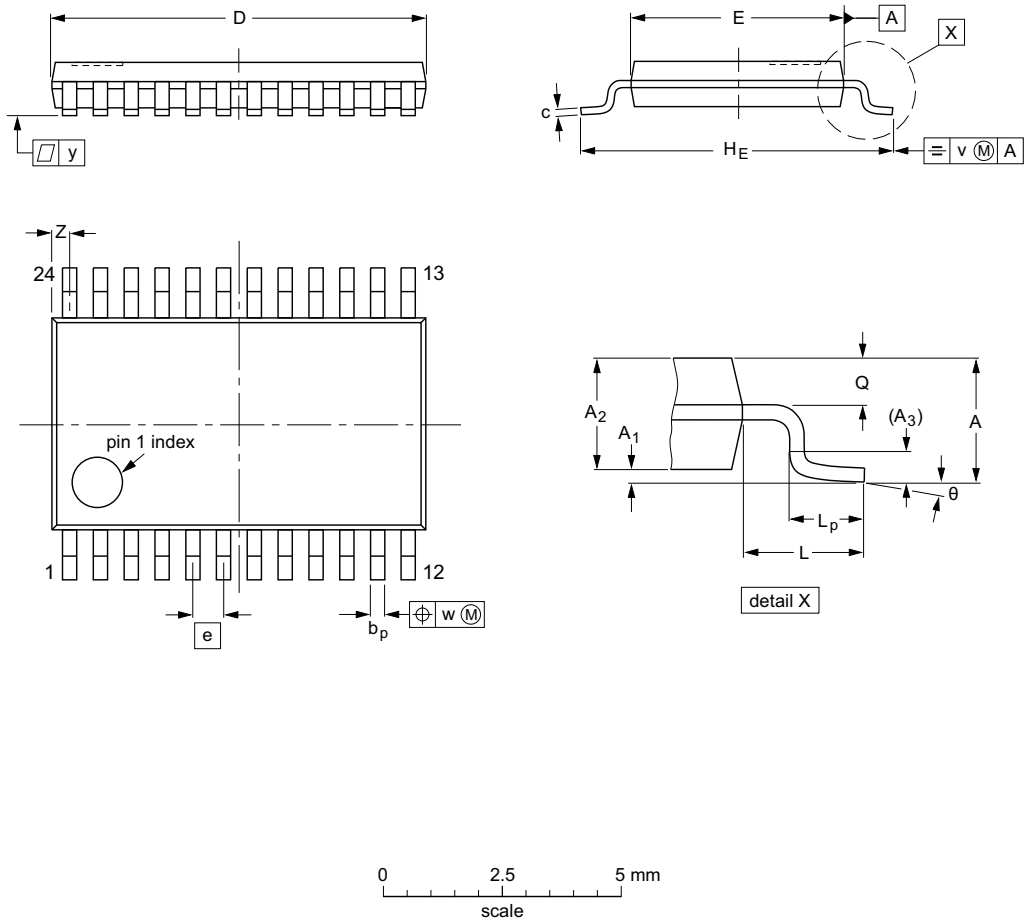


Fig 18. Package outline SOT137-1 (SO24)

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

- Notes**
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT355-1		MO-153				-99-12-27- 03-02-19

Fig 19. Package outline SOT355-1 (TSSOP24)

DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package;
no leads; 24 terminals; body 3.5 x 5.5 x 0.85 mm

SOT815-1

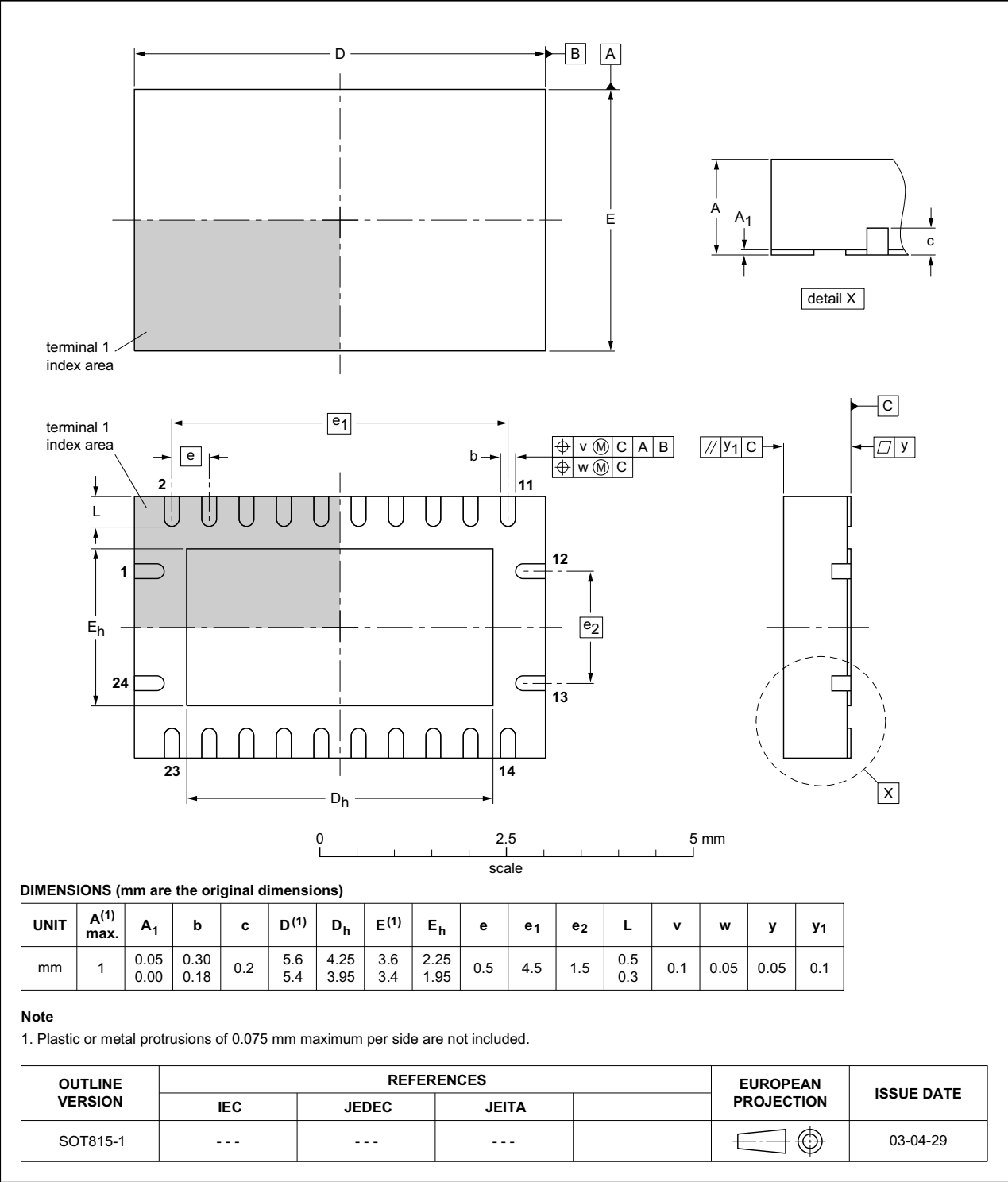


Fig 20. Package outline SOT815-1 (DHVQFN24)

15. Abbreviations

Table 14. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic
MIL	Military

16. Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4067_Q100 v.1	20150522	Product data sheet	-	-

17. Legal information

17.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

17.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

17.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This NXP Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

17.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

18. Contact information

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

19. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Ordering information	2
5	Functional diagram	2
6	Pinning information	5
6.1	Pinning	5
6.2	Pin description	5
7	Functional description	6
8	Limiting values	6
9	Recommended operating conditions	7
10	Static characteristics	8
11	Dynamic characteristics	13
12	Waveforms	16
13	Additional dynamic characteristics	18
14	Package outline	21
15	Abbreviations	24
16	Revision history	24
17	Legal information	25
17.1	Data sheet status	25
17.2	Definitions	25
17.3	Disclaimers	25
17.4	Trademarks	26
18	Contact information	26
19	Contents	27

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP Semiconductors N.V. 2015.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 22 May 2015

Document identifier: 74HC_HCT4067_Q100

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP:

[74HC4067BQ-Q100J](#) [74HC4067D-Q100J](#) [74HC4067PW-Q100J](#) [74HCT4067PW-Q100J](#) [74HCT4067D-Q100J](#)
[74HCT4067BQ-Q100J](#)